



# BGU8053

## Low noise high linearity amplifier

Rev. 2 — 30 December 2013

Product data sheet

## 1. Product profile

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### 1.1 General description

The BGU8053 is a low noise high linearity amplifier for wireless infrastructure applications, equipped with fast shutdown to support TDD systems. The LNA has a high input and output return loss and is designed to operate between 2 GHz and 4 GHz. It is housed in a 2 mm × 2 mm × 0.75 mm 8-terminal plastic thin small outline package. The LNA is ESD protected on all terminals.

### 1.2 Features and benefits

- Low noise performance:  $NF = 0.56$  dB
- High linearity performance:  $IP3O = 36$  dBm
- High input return loss  $> 12$  dB
- High output return loss  $> 20$  dB
- Unconditionally stable up to 20 GHz
- Programmable bias current (via resistor)
- Small 8-terminal leadless package 2 mm × 2 mm × 0.75 mm
- ESD protection on all terminals
- Moisture sensitivity level 1
- Fast shutdown to support TDD systems
- +5 V single supply

### 1.3 Applications

- Wireless infrastructure
- Low noise and high linearity applications
- LTE, W-CDMA, CDMA, GSM
- General purpose wireless applications
- TDD or FDD systems
- Suitable for small cells



### 1.4 Quick reference data

**Table 1. Quick reference data**

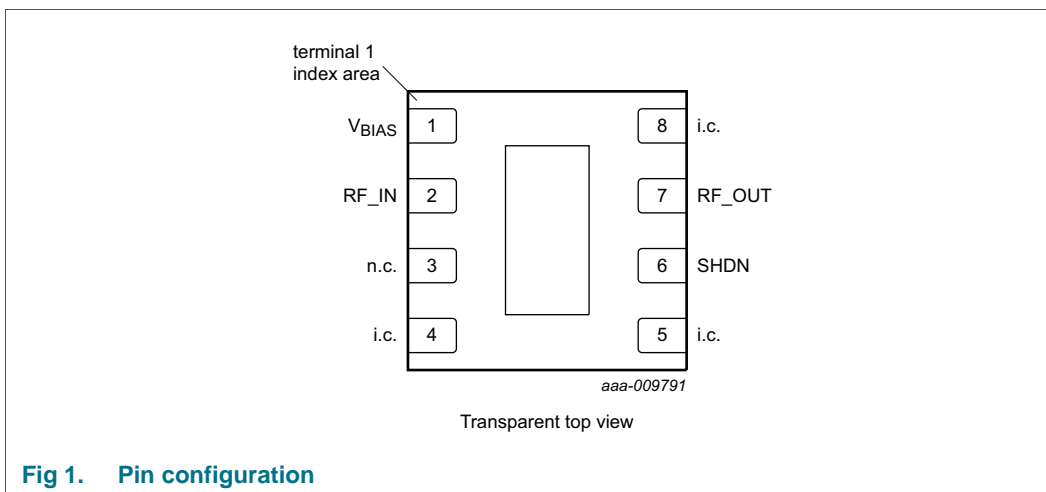
$f = 2500$  MHz;  $V_{CC} = 5$  V;  $T_{amb} = 25$  °C; input and output  $50 \Omega$ ;  $R_{bias} = 5.1$  k $\Omega$ ; unless otherwise specified. All RF parameters are measured in an application board as shown in [Figure 15](#) with components listed in [Table 9](#) optimized for  $f = 2500$  MHz.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I <sub>CC</sub>	supply current	on state	36	48	60	mA
		off state	-	2.8	-	mA
G <sub>ass</sub>	associated gain	on state	17	18.5	20	dB
		off state	-	-23.5	-	dB
NF	noise figure		[1]	0.56	0.75	dB
P <sub>L(1dB)</sub>	output power at 1 dB gain compression		-	18	-	dBm
IP3 <sub>O</sub>	output third-order intercept point	2-tone; tone spacing = 1 MHz; P <sub>i</sub> = -15 dBm per tone	32	36	-	dBm

[1] Connector and Printed-Circuit Board (PCB) losses have been de-embedded.

## 2. Pinning information

### 2.1 Pinning



**Fig 1. Pin configuration**

### 2.2 Pin description

**Table 2. Pin description**

Symbol	Pin	Description
V <sub>BIAS</sub>	1	bias voltage
RF_IN	2	RF input
n.c.	3	not connected
i.c.	4, 5, 8	internally connected. Can be grounded or left open in the application
SHDN	6	shutdown
RF_OUT	7	RF output
GND	exposed die pad	ground

### 3. Ordering information

**Table 3. Ordering information**

Type number	Package		Version
	Name	Description	
BGU8053	HWSO8	plastic thermal enhanced very very thin small outline package; no leads; 8 terminals; body 2 × 2 × 0.75 mm	SOT1327-1

### 4. Limiting values

**Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-	6	V
$V_{ctrl(sd)}$	shutdown control voltage		-	3	V
$I_{CC}$	supply current		-	85	mA
$P_{i(RF)CW}$	continuous waveform RF input power		-	20	dBm
$T_{stg}$	storage temperature		-40	+150	°C
$T_j$	junction temperature		-	150	°C
$P$	power dissipation	$T_{case} \leq 125\text{ °C}$	[1]	510	mW
$V_{ESD}$	electrostatic discharge voltage	Human Body Model (HBM) According to ANSI/ESDA/JEDEC standard JS-001-2010	-	0.9	kV
		Charged Device Model (CDM); According JEDEC standard 22-C101B	-	2	kV

[1] Case is ground solder pad.

### 5. Recommended operating conditions

**Table 5. Characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{CC}$	supply voltage		4.75	5	5.25	V
$Z_0$	characteristic impedance		-	50	-	$\Omega$
$T_{case}$	case temperature		-40	-	+85	°C

### 6. Thermal characteristics

**Table 6. Thermal characteristics**

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-case)}$	thermal resistance from junction to case		[1][2] 50	K/W

[1] Case is ground solder pad.

[2] Thermal resistance measured using infrared measurement technique, device mounted on application board and placed in still air.

## 7. Characteristics

**Table 7. Characteristics**

$f = 2500$  MHz;  $V_{CC} = 5$  V;  $T_{amb} = 25$  °C; input and output  $50 \Omega$ ;  $R_{bias} = 5.1$  k $\Omega$ ; unless otherwise specified. All RF parameters are measured in an application board as shown in [Figure 15](#) with components listed in [Table 9](#) optimized for  $f = 2500$  MHz.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$I_{CC}$	supply current	on state	36	48	60	mA
		off state	-	2.8	-	mA
$G_{ass}$	associated gain	on state	17	18.5	20	dB
		off state	-	-23.5	-	dB
NF	noise figure		[1]	0.56	0.75	dB
$P_{L(1dB)}$	output power at 1 dB gain compression		-	18	-	dBm
IP <sub>3O</sub>	output third-order intercept point	2-tone; tone spacing = 1 MHz; $P_i = -15$ dBm per tone	32	36	-	dBm
		2-tone; tone spacing = 1 MHz; $P_i = -15$ dBm per tone	[2]	30	34	-
RL <sub>in</sub>	input return loss	on state	-	12.2	-	dB
		off state	-	6.3	-	dB
RL <sub>out</sub>	output return loss		-	28.0	-	dB
ISL	isolation		-	22.0	-	dB
$t_{s(pon)}$	power-on settling time	$P_i = -20$ dBm; SHDN (pin 6) from HIGH to LOW	[2]	1.4	-	$\mu$ s
$t_{s(poff)}$	power-off settling time	$P_i = -20$ dBm; SHDN (pin 6) from LOW to HIGH	[2]	0.4	-	$\mu$ s
K	Rollett stability factor	both on state and off state up to $f = 20$ GHz	1	-	-	
$R_{pd(SHDN)}$	pull-down resistance on pin SHDN		-	30	-	k $\Omega$

[1] Connector and Printed-Circuit Board (PCB) losses have been de-embedded.

[2] For TDD systems where fast switching is required, it is recommended to change C1 and C2 to 100 pF.

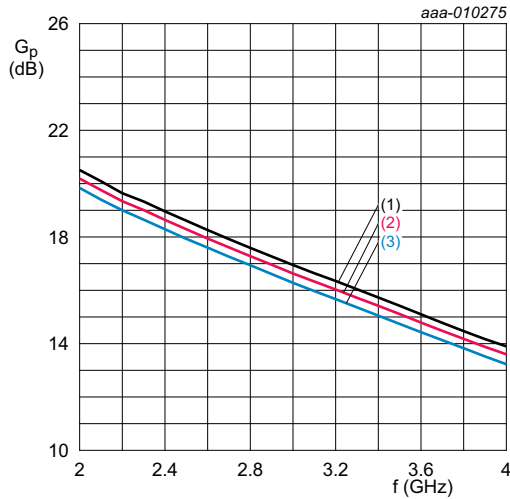
**Table 8. Shutdown control**

$V_{CC} = 5$  V;  $T_{amb} = 25$  °C; input and output  $50 \Omega$ ;  $R_{bias} = 5.1$  k $\Omega$ ; unless otherwise specified. All RF parameters are measured in an application board as shown in [Figure 15](#) with components listed in [Table 9](#) optimized for  $f = 2500$  MHz.

State	$V_{ctrl(sd)}$ [1] (V)
on state	$\leq 0.6$
off state	$\geq 1.2$

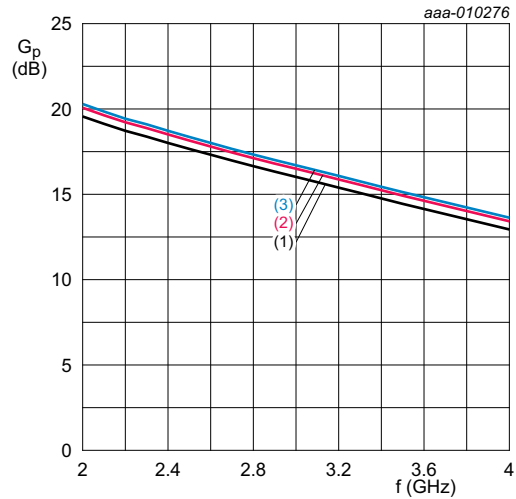
[1] Voltage on pin 6 (SHDN).

7.1 Graphs



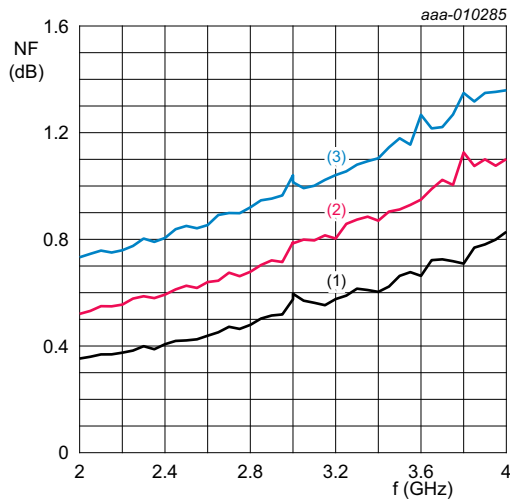
$V_{CC} = 5\text{ V}; I_{CC} = 48\text{ mA}$ .  
 (1)  $T_{amb} = -40\text{ }^{\circ}\text{C}$   
 (2)  $T_{amb} = +25\text{ }^{\circ}\text{C}$   
 (3)  $T_{amb} = +85\text{ }^{\circ}\text{C}$

**Fig 2. Power gain as a function of frequency; typical values**



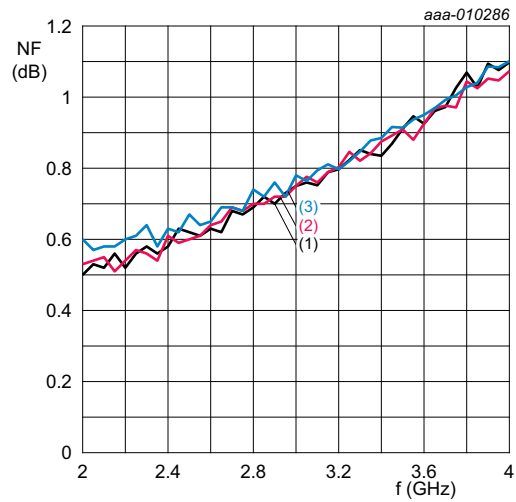
$V_{CC} = 5\text{ V}; T_{amb} = 25\text{ }^{\circ}\text{C}$ .  
 (1)  $I_{CC} = 30\text{ mA}$   
 (2)  $I_{CC} = 45\text{ mA}$   
 (3)  $I_{CC} = 60\text{ mA}$

**Fig 3. Power gain as a function of frequency; typical values**



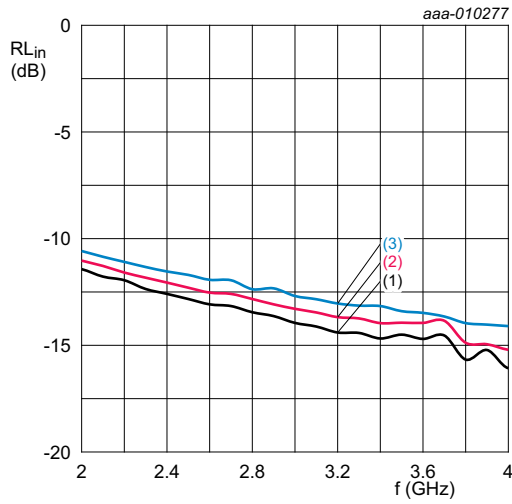
$V_{CC} = 5\text{ V}; I_{CC} = 48\text{ mA}$ .  
 (1)  $T_{amb} = -40\text{ }^{\circ}\text{C}$   
 (2)  $T_{amb} = +25\text{ }^{\circ}\text{C}$   
 (3)  $T_{amb} = +85\text{ }^{\circ}\text{C}$

**Fig 4. Noise figure as a function of frequency; typical values**



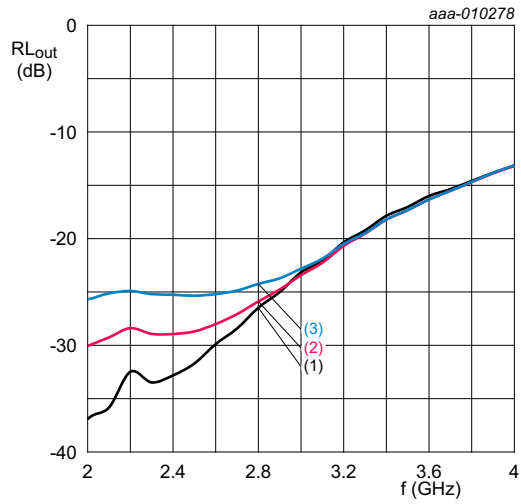
$V_{CC} = 5\text{ V}; T_{amb} = 25\text{ }^{\circ}\text{C}$ .  
 (1)  $I_{CC} = 30\text{ mA}$   
 (2)  $I_{CC} = 45\text{ mA}$   
 (3)  $I_{CC} = 60\text{ mA}$

**Fig 5. Noise figure as a function of frequency; typical values**



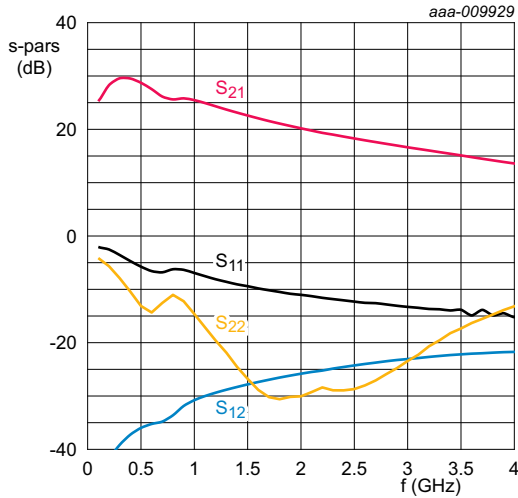
$V_{CC} = 5\text{ V}; I_{CC} = 48\text{ mA}$ .  
 (1)  $T_{amb} = -40\text{ }^{\circ}\text{C}$   
 (2)  $T_{amb} = +25\text{ }^{\circ}\text{C}$   
 (3)  $T_{amb} = +85\text{ }^{\circ}\text{C}$

**Fig 6. Input return loss as a function of frequency; typical values**



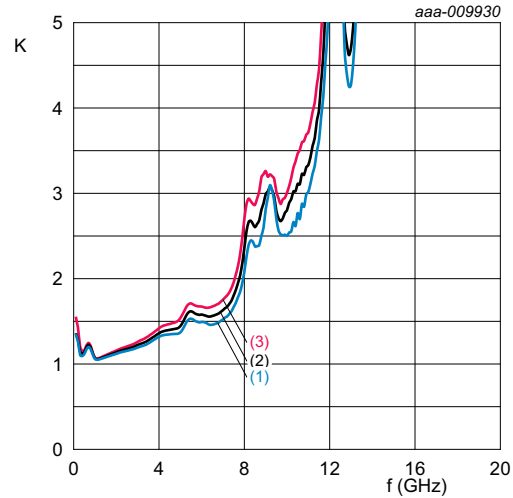
$V_{CC} = 5\text{ V}; I_{CC} = 48\text{ mA}$ .  
 (1)  $T_{amb} = -40\text{ }^{\circ}\text{C}$   
 (2)  $T_{amb} = +25\text{ }^{\circ}\text{C}$   
 (3)  $T_{amb} = +85\text{ }^{\circ}\text{C}$

**Fig 7. Output return loss as a function of frequency; typical values**



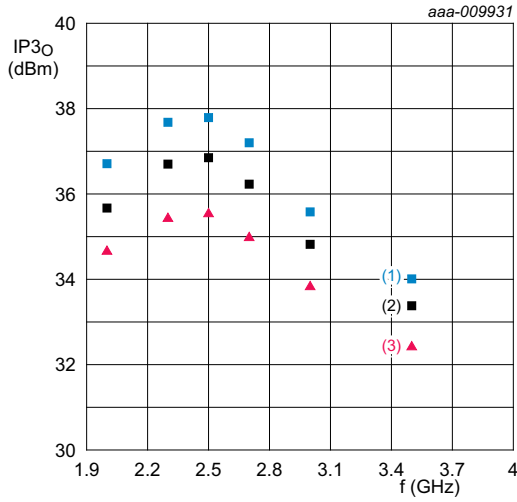
$V_{CC} = 5\text{ V}; T_{amb} = 25\text{ }^{\circ}\text{C}; I_{CC} = 48\text{ mA}$ .

**Fig 8. Wideband S-parameters as function of frequency; typical values**



$V_{CC} = 5\text{ V}; I_{CC} = 48\text{ mA}$ .  
 (1)  $T_{amb} = -40\text{ }^{\circ}\text{C}$   
 (2)  $T_{amb} = +25\text{ }^{\circ}\text{C}$   
 (3)  $T_{amb} = +85\text{ }^{\circ}\text{C}$

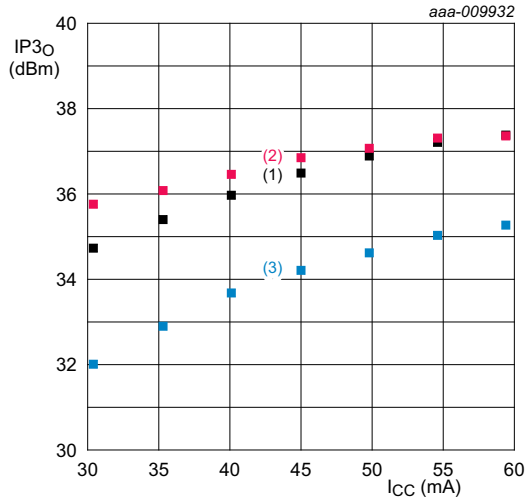
**Fig 9. Rollet stability factor as a function of frequency; typical values**



$V_{CC} = 5\text{ V}$ ;  $P_i = -15\text{ dBm}$  per tone;  $I_{CC} = 48\text{ mA}$ .

- (1)  $T_{amb} = -40\text{ °C}$
- (2)  $T_{amb} = +25\text{ °C}$
- (3)  $T_{amb} = +85\text{ °C}$

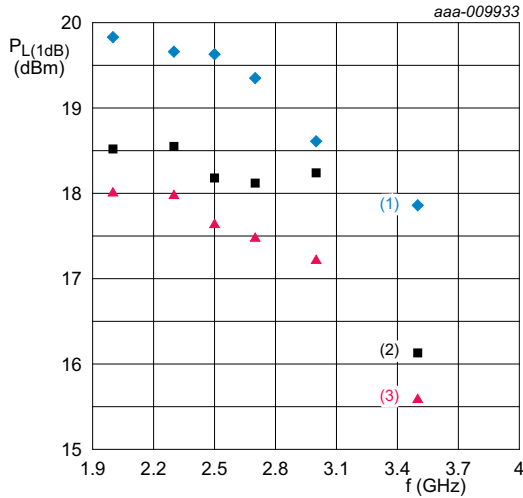
**Fig 10. Output third-order intercept point as a function of frequency; typical values**



$V_{CC} = 5\text{ V}$ ;  $P_i = -15\text{ dBm}$  per tone;  $T_{amb} = 25\text{ °C}$ .

- (1)  $f = 2000\text{ MHz}$
- (2)  $f = 2500\text{ MHz}$
- (3)  $f = 3000\text{ MHz}$

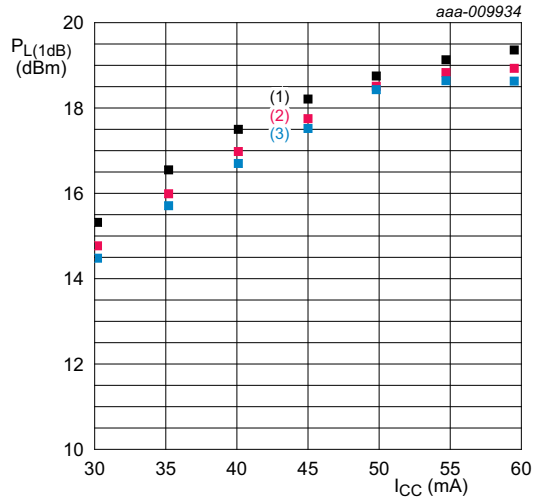
**Fig 11. Output third-order intercept point as a function of supply current; typical values**



$V_{CC} = 5\text{ V}$ ;  $I_{CC} = 48\text{ mA}$ .

- (1)  $T_{amb} = -40\text{ °C}$
- (2)  $T_{amb} = +25\text{ °C}$
- (3)  $T_{amb} = +85\text{ °C}$

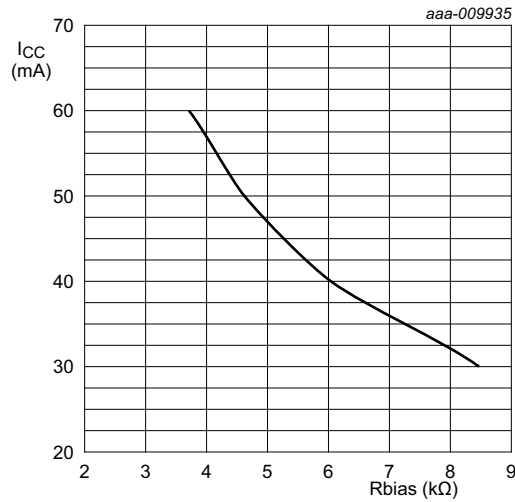
**Fig 12. Output power at 1 dB gain compression as a function of frequency; typical values**



$V_{CC} = 5\text{ V}$ ;  $T_{amb} = 25\text{ °C}$ .

- (1)  $f = 2000\text{ MHz}$
- (2)  $f = 2500\text{ MHz}$
- (3)  $f = 3000\text{ MHz}$

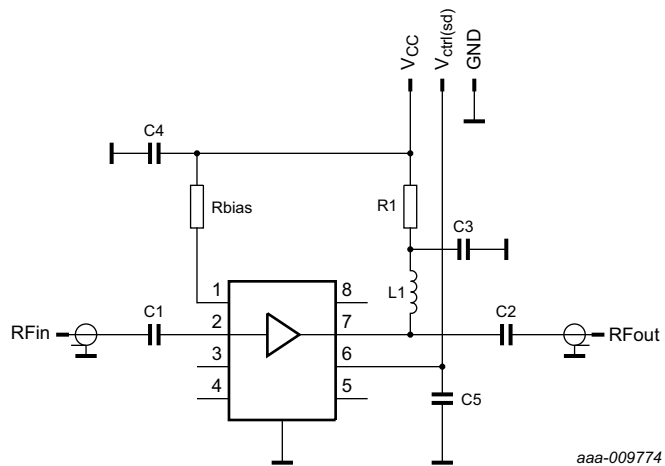
**Fig 13. Output power at 1 dB gain compression as a function of supply current; typical values**



V<sub>CC</sub> = 5 V.

Fig 14. Supply current as a function of R<sub>bias</sub>; typical values

## 8. Application information



See [Table 9](#) for a list of components.

Fig 15. Schematic of application board

Table 9. List of components

See [Figure 15](#) for schematics.

Component	Description	Value	Remarks
C1, C2	capacitor	100 nF	
		100 pF	recommended for TDD systems
C3, C5	capacitor	10 pF	
C4	capacitor	10 nF	



**Table 9. List of components ...continued**  
See [Figure 15](#) for schematics.

Component	Description	Value	Remarks
L1	inductor	15 nH	
R1	resistor	10 $\Omega$	
Rbias	resistor	5.1 k $\Omega$	

**Table 10. Typical performance BGU8053 application board**

All RF parameters are measured at the application board as shown in [Figure 15](#) with the components as listed in [Table 9](#) while optimized for:  $f = 2500$  MHz;  $V_{CC} = 5$  V;  $I_{CC} = 48$  mA and  $T_{amb} = 25$  °C.

Symbol	Parameter	f (MHz)								
		2000	2300	2500	2700	3000	3400	3500	3800	
$G_{ass}$	associated gain	20.2	19.0	18.3	17.6	16.6	15.4	15.1	14.2	
$RL_{in}$	input return loss	11.0	11.8	12.3	12.6	13.3	14.0	13.8	14.9	
$RL_{out}$	output return loss	30.1	28.9	28.7	27.1	23.4	18.2	17.3	14.7	
$P_{L(1dB)}$	output power at 1 dB gain compression	18.5	18.6	18.2	18.1	18.2	16.4	16.1	14.4	
$IP3O$	output third-order intercept point	[1]	35.7	36.7	36.8	36.2	34.8	36.2	33.4	33.0
		[1][2]	34.9	35.9	34.5	36.0	32.1	35.3	31.7	31.6
NF	noise figure	[3]	0.52	0.59	0.63	0.68	0.79	0.81	0.83	0.96

[1] 2-Tone; tone spacing = 1 MHz;  $P_1 = -15$  dBm per tone.

[2] For TDD systems C1 and C2 have to be 100 pF.

[3] Connector and board losses not de-embedded.

9. Package outline

HWSON8: plastic thermal enhanced very very thin small outline package; no leads; 8 terminals; body 2 x 2 x 0.75 mm

SOT1327-1

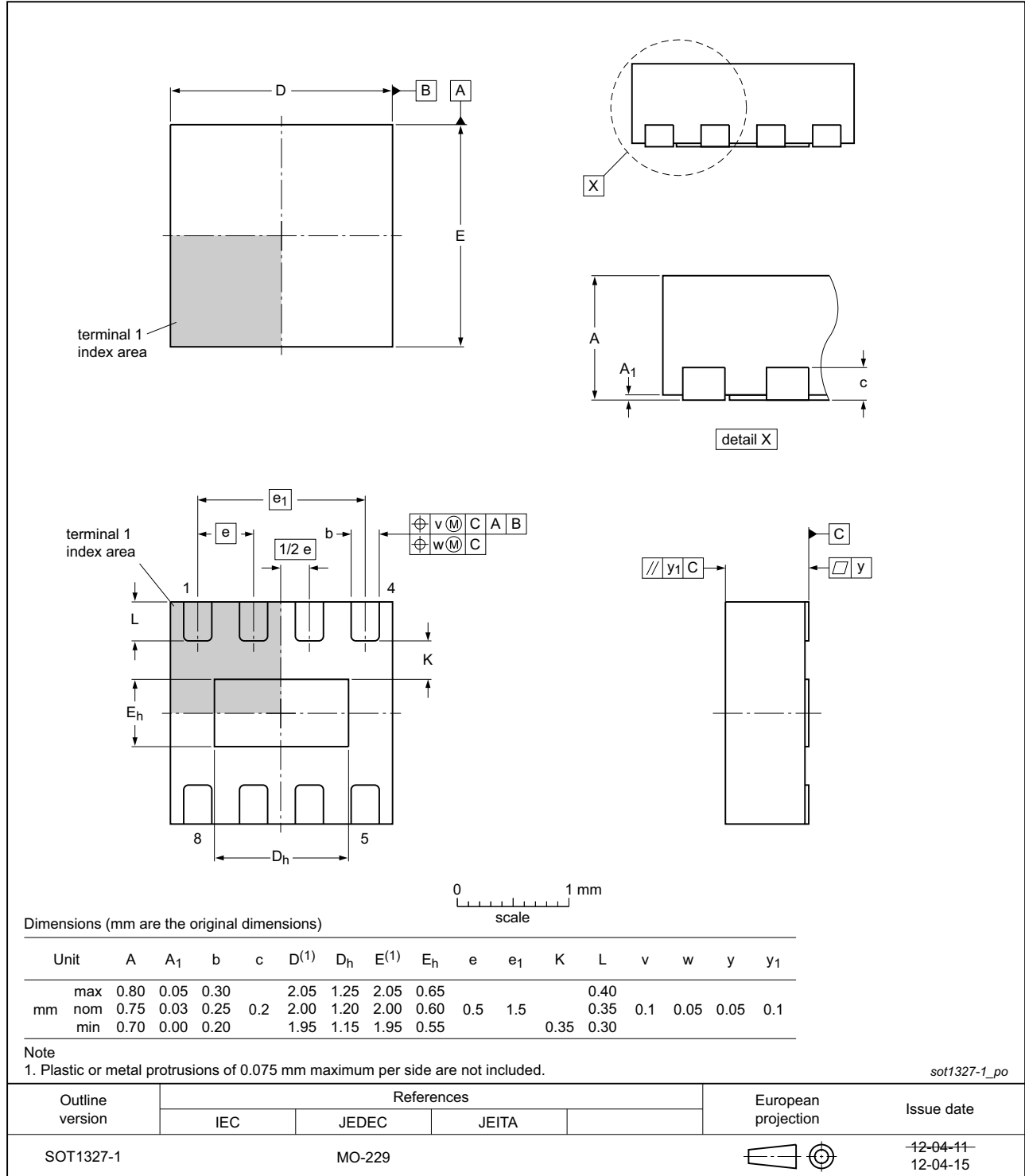


Fig 16. Package outline SOT1327-1 (HWSON8)

## 10. Abbreviations

Table 11. Abbreviations

Acronym	Description
CDMA	Code Division Multiple Access
ESD	ElectroStatic Discharge
FDD	Frequency-Division Duplexing
GSM	Global System for Mobile Communication
LNA	Low Noise Amplifier
LTE	Long Term Evolution
RF	Radio Frequency
TDD	Time-Division Duplexing
W-CDMA	Wideband Code Division Multiple Access

## 11. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BGU8053 v.2	20131230	Product data sheet	-	BGU8053 v.1
Modifications:	<ul style="list-style-type: none"> <li><a href="#">Table 4 on page 3</a>: The maximum value for <math>V_{ctrl(sd)}</math> has been corrected to 3 V.</li> </ul>			
BGU8053 v.1	20131127	Product data sheet	-	-

## 12. Legal information

### 12.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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